

## **4A, 400V - 600V Hyperfast Dual Diodes**

The RHRD440CC, RHRD460CC, RHRD440CCS and RHRD460CCS are hyperfast dual diodes with soft recovery characteristics ( $t_{rr} < 30\text{ns}$ ). They have half the recovery time of ultrafast diodes and are silicon nitride passivated ion-implanted epitaxial planar construction.

These devices are intended for use as freewheeling/clamping diodes and rectifiers in a variety of switching power supplies and other power switching applications. Their low stored charge and hyperfast soft recovery minimize ringing and electrical noise in many power switching circuits reducing power loss in the switching transistors.

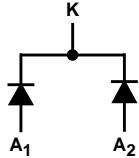
Formerly developmental type TA49055.

### **Ordering Information**

PART NUMBER	PACKAGE	BRAND
RHRD440CC	TO-251AA	HR440C
RHRD460CC	TO-251AA	HR460C
RHRD440CCS	TO-252AA	HR440C
RHRD460CCS	TO-252AA	HR460C

NOTE: When ordering, use the entire part number. Add the suffix 9A to obtain the TO-252 variant in tape and reel, e.g. RHRD460CCS9A.

### **Symbol**



### **Features**

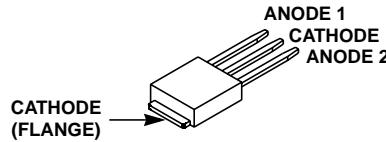
- Hyperfast with Soft Recovery ..... <30ns
- Operating Temperature ..... 175°C
- Reverse Voltage Up To ..... 600V
- Avalanche Energy Rated
- Planar Construction
- Related Literature
  - TB334 "Guidelines for Soldering Surface Mount Components to PC Boards"

### **Applications**

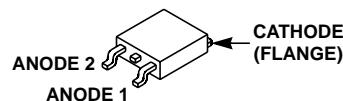
- Switching Power Supplies
- Power Switching Circuits
- General Purpose

### **Packaging**

**JEDEC TO-251AA**



**JEDEC TO-252AA**



### **Absolute Maximum Ratings (Per Leg) $T_C = 25^\circ\text{C}$ , Unless Otherwise Specified**

	RHRD440CC, RHRD440CCS	RHRD460CC, RHRD460CCS	UNITS
Peak Repetitive Reverse Voltage .....	$V_{RRM}$	400	V
Working Peak Reverse Voltage .....	$V_{RWM}$	400	V
DC Blocking Voltage .....	$V_R$	400	V
Average Rectified Forward Current .....	$I_{F(AV)}$	4	A
$T_C = 155^\circ\text{C}$			
Repetitive Peak Surge Current .....	$I_{FRM}$	8	A
Square Wave, 20kHz			
Nonrepetitive Peak Surge Current .....	$I_{FSM}$	40	A
Halfwave, 1 Phase, 60Hz			
Maximum Power Dissipation .....	$P_D$	50	W
Avalanche Energy (See Figures 10 and 11) .....	$E_{AVL}$	10	mJ
Operating and Storage Temperature .....	$T_{STG}, T_J$	-65 to 175	$^\circ\text{C}$
Maximum Temperature for Soldering			
Leads at 0.063in (1.6mm) from Case for 10s.....	$T_L$	300	$^\circ\text{C}$
Package Body for 10s, see Tech Brief 334 .....	$T_{pkg}$	260	$^\circ\text{C}$

# RHRD440CC, RHRD460CC, RHRD440CCS, RHRD460CCS

**Electrical Specifications** (Per Leg)  $T_C = 25^\circ\text{C}$ , Unless Otherwise Specified

SYMBOL	TEST CONDITION	RHRD440CC, RHRD440CCS			RHRD460CC, RHRD460CCS			UNITS
		MIN	TYP	MAX	MIN	TYP	MAX	
$V_F$	$I_F = 4\text{A}$	-	-	2.1	-	-	2.1	V
	$I_F = 4\text{A}, T_C = 150^\circ\text{C}$	-	-	1.7	-	-	1.7	V
$I_R$	$V_R = 400\text{V}$	-	-	100	-	-	-	$\mu\text{A}$
	$V_R = 600\text{V}$	-	-	-	-	-	100	$\mu\text{A}$
	$V_R = 400\text{V}, T_C = 150^\circ\text{C}$	-	-	500	-	-	-	$\mu\text{A}$
	$V_R = 600\text{V}, T_C = 150^\circ\text{C}$	-	-	-	-	-	500	$\mu\text{A}$
$t_{rr}$	$I_F = 1\text{A}, dI_F/dt = 200\text{A}/\mu\text{s}$	-	-	30	-	-	30	ns
	$I_F = 4\text{A}, dI_F/dt = 200\text{A}/\mu\text{s}$	-	-	35	-	-	35	ns
$t_a$	$I_F = 4\text{A}, dI_F/dt = 200\text{A}/\mu\text{s}$	-	16	-	-	16	-	ns
$t_b$	$I_F = 4\text{A}, dI_F/dt = 200\text{A}/\mu\text{s}$	-	7	-	-	7	-	ns
$Q_{RR}$	$I_F = 4\text{A}, dI_F/dt = 200\text{A}/\mu\text{s}$	-	45	-	-	45	-	nC
$C_J$	$V_R = 10\text{V}, I_F = 0\text{A}$	-	15	-	-	15	-	pf
$R_{\theta JC}$		-	-	3	-	-	3	$^\circ\text{C}/\text{W}$

## DEFINITIONS

$V_F$  = Instantaneous forward voltage ( $pw = 300\mu\text{s}$ ,  $D = 2\%$ ).

$I_R$  = Instantaneous reverse current.

$t_{rr}$  = Reverse recovery time (See Figure 9), summation of  $t_a + t_b$ .

$t_a$  = Time to reach peak reverse current (See Figure 9).

$t_b$  = Time from peak  $I_{RM}$  to projected zero crossing of  $I_{RM}$  based on a straight line from peak  $I_{RM}$  through 25% of  $I_{RM}$  (See Figure 9).

$Q_{RR}$  = Reverse recovery charge.

$C_J$  = Junction Capacitance.

$R_{\theta JC}$  = Thermal resistance junction to case.

$pw$  = Pulse width.

D = Duty cycle.

## Typical Performance Curves

Unless Otherwise Specified

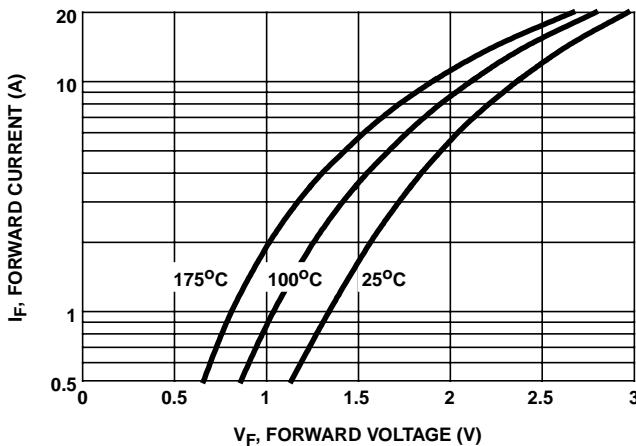


FIGURE 1. FORWARD CURRENT vs FORWARD VOLTAGE

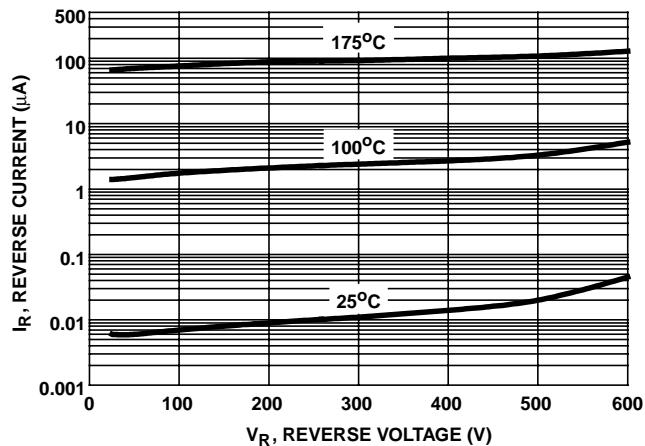


FIGURE 2. REVERSE CURRENT vs REVERSE VOLTAGE

**Typical Performance Curves** Unless Otherwise Specified (Continued)

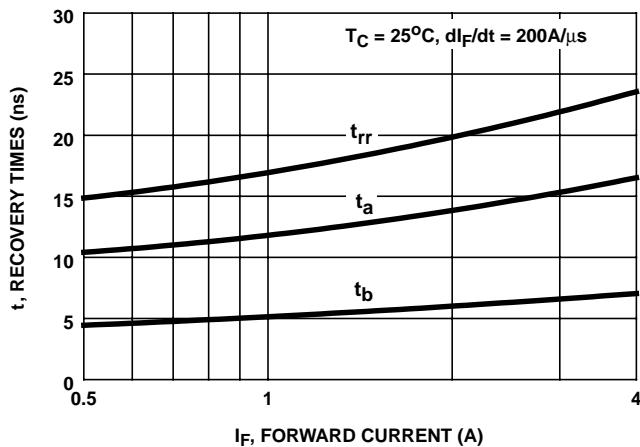


FIGURE 3.  $t_{rr}$ ,  $t_a$  AND  $t_b$  CURVES vs FORWARD CURRENT

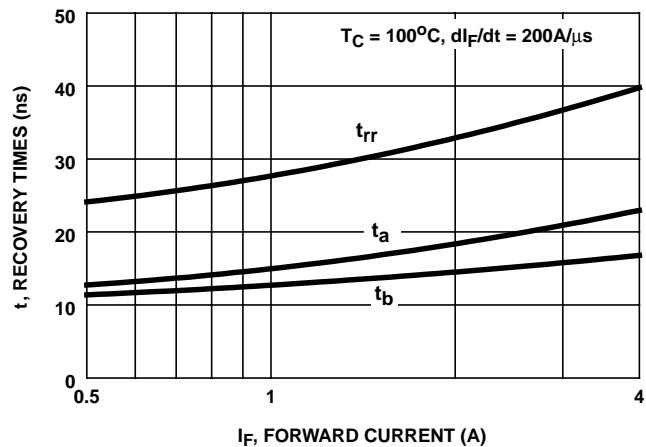


FIGURE 4.  $t_{rr}$ ,  $t_a$  AND  $t_b$  CURVES vs FORWARD CURRENT

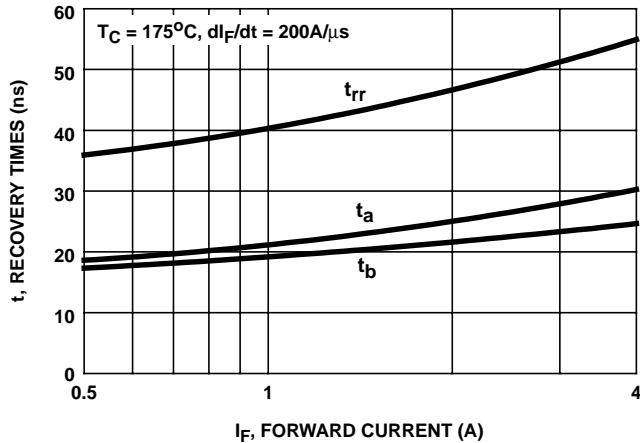


FIGURE 5.  $t_{rr}$ ,  $t_a$  AND  $t_b$  CURVES vs FORWARD CURRENT

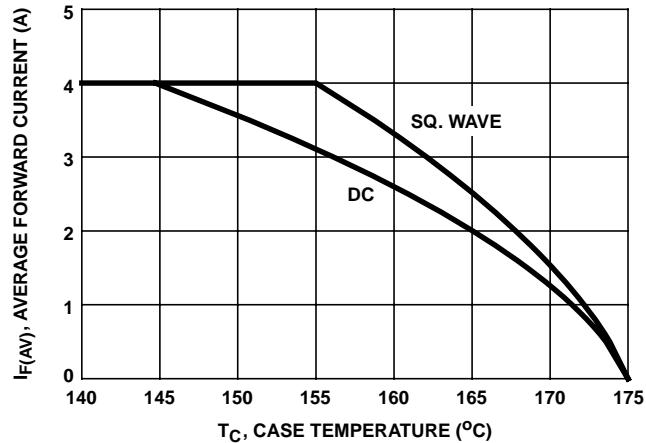


FIGURE 6. CURRENT DERATING CURVE

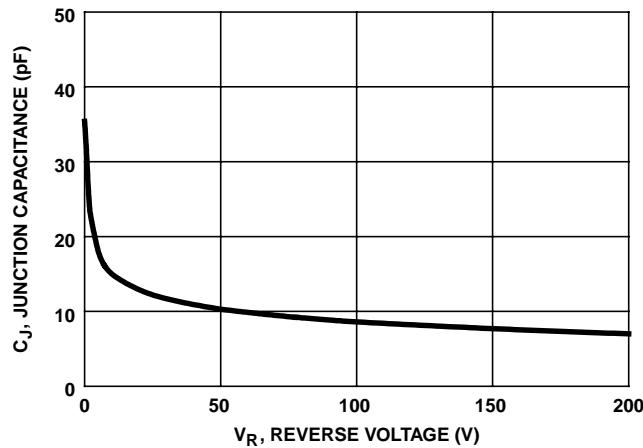


FIGURE 7. JUNCTION CAPACITANCE vs REVERSE VOLTAGE

## Test Circuits and Waveforms

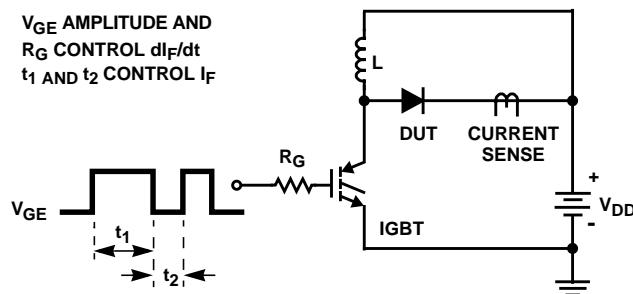


FIGURE 8. t<sub>rr</sub> TEST CIRCUIT

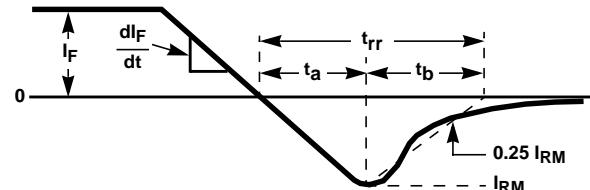


FIGURE 9. t<sub>rr</sub> WAVEFORMS AND DEFINITIONS

I<sub>MAX</sub> = 1A  
L = 20mH  
R < 0.1Ω  
E<sub>AVL</sub> = 1/2LI<sup>2</sup> [V<sub>R(AVL)</sub>/(V<sub>R(AVL)</sub> - V<sub>DD</sub>)]  
Q<sub>1</sub> = IGBT (BV<sub>CES</sub> > DUT V<sub>R(AVL)</sub>)

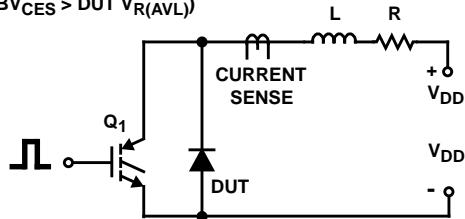


FIGURE 10. AVALANCHE ENERGY TEST CIRCUIT

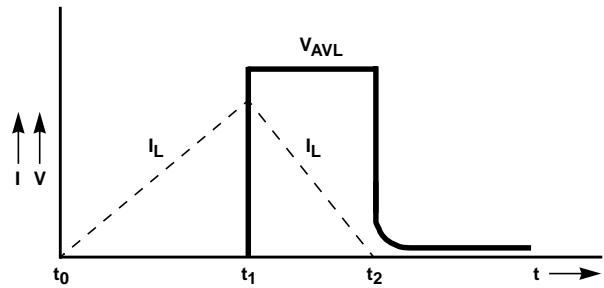


FIGURE 11. AVALANCHE CURRENT AND VOLTAGE WAVEFORMS

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